5MM PHOTOTRANSISTOR ST-7L5P-FH



Features

Fast response time High photo sensitivity Pb free The product itself will remain within RoHS compliant version. **Application** Infrared applied system

Camera

Printer

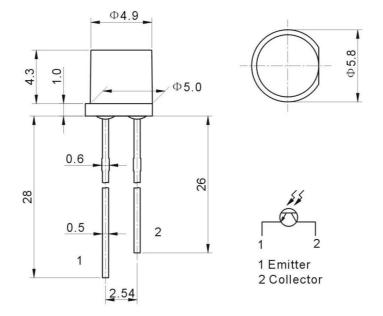
Optoelectronic switch

Description

ST-7L5P-FH is a high speed and high sensitive NPN silicon phototransistor molded in a standard ϕ 5 mm package. Due to is water clear epoxy the device is sensitive to visible and near infrared radiation.



PACKAGE DIMENSIONS



NOTES:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.25mm(.010") unless otherwise noted.
- 3. Lead spacing is measured where the leads emerge from the package.

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ABSOLUTE MAXIMUM RATINGS AT TA =25°C

Parameter	Symbol	Rating	Unit
Power Dissipation at (or below) 25°CFree Air Temperature	Рс	75	mW
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Collector Voltage	V _{ECO}	5	V
Collector Current	Ic	20	mA
Operating Temperature	Topr	-25~+85	°C
Storage Temperature	Tstg	-40~+85	°C
Soldering Temperature (1/16 inch from body for 5 seconds)	Tsol	260	°C

Notes: *1:Soldering time≦5 seconds.

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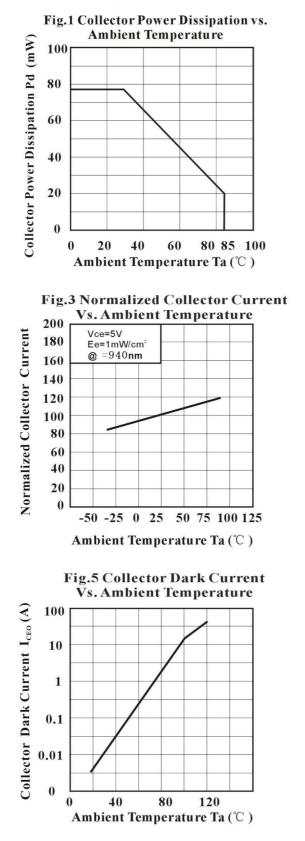
ELECTRICAL OFFICIAL CHARACTERISTICS AT TA 25 C								
Param	eter	Symbol	Min.	Тур.	Max.	Unit	Test Condition	
Collector Dark Current		Ιςεο			100	nA	Ie=0mW/cm ² V _{CE} =20V	
On State Collecto	or Current	I _{C(on)}	0.7	2.0			Ie=1mW/cm ² V _{CE} =5V	
Emitter-Collector Breakdown Voltage		BVCEO	30		100	V	I _C =100 µ A Ie=0mW/cm ²	
Collector - Emitter Breakdown Voltage		BV _{ECO}	6.5			V	I _C =100 µ A Ie=0mW/cm ²	
Collector-Emitter Saturation Voltage		V _{CE(sat)}			0.2	V	I _C =2mA Ie=1mW/cm ²	
Current gain		h _{FE}	800		1800	μA	V _{CE} =5V Ic=2mW/cm ²	
Wavelength of Peak Sensitivity		λp		940		nm		
Range of Spectral Bandwidth		λο.5	450		1100	nm		
Response Time	Rise Time	tr		15		μS	V _{CE} =5V Ic=1mA	
	Fall Time	tf		15		μS	$R_L=1000\Omega$	
Collector-Capacitance		Ссв	5.4	6.4	7.4	PF	f=1MHz V _{CB} =3V	

ELECTRICAL OPTICAL CHARACTERISTICS AT TA=25°C

SMM PHOTOTRANSISTOR



Typical Electrical-Optical Characteristics Curves



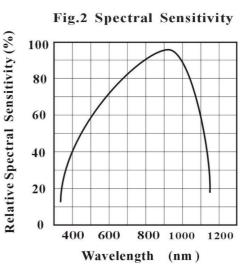


Fig.4 Relative Collector Current

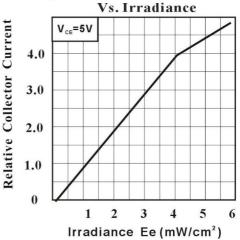
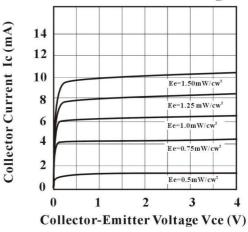


Fig.6 Collector Current vs. Collector-Emitter Voltage



SMM PHOTOTRANSISTOR



Packing Quantity Specification

- 1. 1000Pcs/1Bag,10 Bag/1Box
- 2. 4Boxes/1Carton

Label Form Specification



- · PRODUCT: Part Number
- · CODE NO.: Product Serial Number
- QTY: Packing Quantity
- · LOT No: Lot Number
- · REMARKS:Remarks

Notes

Lead Forming

4. Avoiding applying any stress to the lead frame while the Phototransistors are at high temperature particularly when soldering.

5.Dip and hand soldering should not be done more than one time

6.After soldering the Phototransistors, the epoxy bulb should be protected from mechanical shock or vibration until the Phototransistors return to room temperature.

7.A rapid-rate process is not recommended for cooling the Phototransistors down from the peak temperature.

8.Although the recommended soldering conditions are specified in the above table, dip or hand soldering at the lowest possible temperature is desirable for the Phototransistors.

9. Wave soldering parameter must be set and maintain according to recommended temperature and dwell time in the solder wave.

SMM PHOTOTRANSISTOR



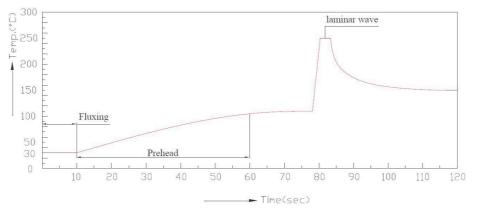
Soldering

1. Careful attention should be paid during soldering. When soldering, leave more than 3mm from solder joint to epoxy bulb, and soldering beyond the base of the tie bar is recommended.

2. Recommended soldering conditions:

Hand	dSoldering	DIP Soldering		
Temp. at tip of iron	300°C Max. (30W Max.)	Preheat temp.	100°C Max. (60 sec Max.)	
Soldering time	3 sec Max.	Bath temp. & time	260 Max., 5 sec Max	
	3mm Min.(From solder		3mm Min. (From solder joint	
Distance	joint to epoxy bulb)	Distance	to epoxy bulb)	

3. Recommended soldering profile



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